



## Algebraic localization-delocalization transition in a biased 1D disorder potential G.Berthet, L. Lavoine, M.K Parit, A. Brolis, A. Boissé, T. Bourdel Laboratoire Charles Fabry, Institut d'Optique Graduate School,



Anderson localization phenomena are strongly modified when adding bias force, that is equivalent to a voltage in condensed matter. Experimentally, we launch a non-interacting <sup>39</sup>K Bose-Einstein condensate in a 1D disordered potential induced by a far-off-resonance laser speckle, while controlling a bias force, We observe a transition between algebraic localization and delocalization as a function of our control parameter that is the relative strength of the disorder against the bias force. We demonstrate that the transition is intrinsically energy independent and that the initial velocity of the wave-packet only plays a role through an effective disorder strength due to the correlation of the disorder.

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